NSN 5962-01-372-5963

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-372-5963

view Offilite at https://defobasegroup.com/hsr//5502-01-5/2-5505
Body Length:
Between 1.470 inches and 1.490 inches
Body Width:
Between 0.590 inches and 0.610 inches
Body Height:
Between 0.212 inches and 0.232 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Milstar
Features Provided:
Electrostatic sensitive and radiation hardened and programmed and ultraviolet erasable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
D-10 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed read only memory (mdm tdbb)
Voltage Rating And Type Per Characteristic:
-0.6 volts power source and 6.25 volts power source
Memory Device Type:
Eprom
Memory Capacity:
32k x 8
Special Features:
Electrostatic discharge sens/hardness critical; altered item, programmed device is sv258-0084-010 cage 95105 checksum 7555
Nuclear Hardness Critical Feature:
Hardened

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Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

NSN 5962-01-372-5963

Memory Microcircuit - Page 2 of 2



Terminal Type A	nd Quantity:
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28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0